TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

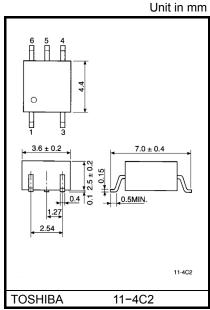
TLP112A

Digital Logic Isolation
Line Receiver
Power Supply Control Feedback Control
Switching Power Supply
Transistor Inverter

The TOSHIBA mini flat coupler TLP112A is a small outline coupler, suitable for surface mount assembly.

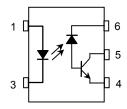
TLP112A consists of a high output power GaAlAs light emitting diode, optically coupled to a high speed detector of one chip photodiode—transistor.

- Isolation voltage: 2500Vrms (min.)
- Switching speed: t_{pHL} =0.8 μ s, t_{pLH} =0.8 μ s(max.)(RL=1.9 μ 2)
- TTL compatible
- UL recognized: UL1577, file no. E67349



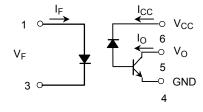
Weight: 0.09g

Pin Configuration(top view)



- 1: Anode
- 3: Cathode
- 4: Emitter (GND)
- 5: Collector (Output)
- 6: V_{CC}

Schematic



Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
LED	Forward current	(Note 1)	lF	20	mA
	Pulse forward current	(Note 2)	I _{FP}	40	mA
	Peak transient forward current	(Note 3)	I _{FPT}	1	Α
	Reverse voltage		V_{R}	5	٧
	Output current		ΙO	8	mA
or	Peak output current		IOP	16	mA
Detector	Supply voltage		V _{CC}	-0.5~15	V
ă	Output voltage		Vo	-0.5~15	V
	Output power dissipation	(Note 4)	PO	100	mW
Оре	perating temperature range		T _{opr}	-55~100	°C
Sto	Storage temperature range		T _{stg}	-55~125	°C
Lea	Lead soldering temperature(10s)		T _{sol}	260	°C
	Isolation voltage (AC, 1min., R.H.≤ 60%, Note 5		BVS	2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- (Note 1) Derate 0.36mA / °C above 70°C.
- (Note 2) 50% duty cycle, 1ms pulse width. Derate 0.72mA / °C above 70°C.
- (Note 3) Pulse width $\leq 1\mu s$, 300pps.
- (Note 4) Derate 1.8mW / °C above 70°C.

Electrical Characteristics(Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit	
LED	Forward voltage	V _F	I _F =16mA	1.22	1.42	1.72	V	
	Forward voltage temperature coefficient	ΔV _F / ΔTa	I _F =16mA	_	-2	_	mV / °C	
	Reverse current	I _R	V _R =3V	_	_	10	μΑ	
	Capacitance between terminals	C _T	V _F =0, f=1MHz	_	30	_	pF	
Detector	High level output current	I _{OH(1)}	I _F =0mA, V _{CC} =V _O =5.5V	_	3	500	nA	
		I _{OH(2)}	I _F =0mA, V _{CC} =V _O =15V	_	_	5	μА	
		Іон	I _F =0mA, V _{CC} =V _O =15V Ta=70°C	_	_	50		
	High level supply current	Іссн	I _F =0mA, V _{CC} =15V	_	0.01	1	μΑ	
Coupled	Current transfer ratio	I _O / I _F	I _F =16mA, V _{CC} =4.5V V _O =0.4V	20	_	_	%	
	Low level output voltage	V _{OL}	I _F =16mA, V _{CC} =4.5V I _O =2.4mA	_	_	0.4	V	
	Isolation resistance	R _S	R.H.≤ 60% V _S =500V DC (Note 5	5×10 ¹⁰	10 ¹⁴	_	Ω	
	Stray capacitance between input to output	CS	V _S =0, f=1MHz (Note 5	_	0.8	_	pF	

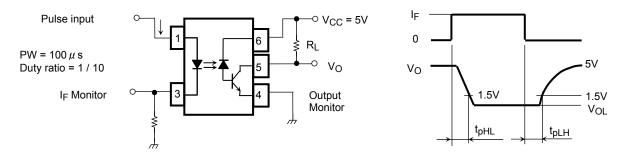
Switching Characteristics(Ta = 25°C)

Characteristic	Symbol	Test Cir- cuit	Test Condition	Min.	Тур.	Max.	Unit
Propagation delay time (H→L)	t _{pHL}	1	I_F =0→16mA V_{CC} =5V, R_L =1.9kΩ	_	_	0.8	μs
Propagation delay time (L→H)	t _{pLH}	1	I_F =16 \rightarrow 0mA V_{CC} =5V, R_L =1.9k Ω	_	_	0.8	μs
Common mode transient imunity at high output level	CM _H	2	I_F =0mA, V_{CM} =200 V_{p-p} RL=4.1kΩ	_	1500	_	V / µs
Common mode transient imunity at low output level	CML	2	I_F =16mA, V_{CM} =200 V_{p-p} RL=4.1kΩ	_	-1500	-	V / µs

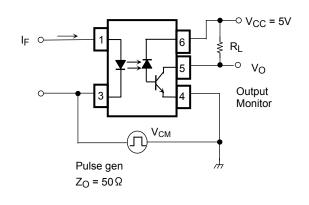
(Note 5) Device considered a two–terminal device: Pins 1 and 3 shorted together and pin 4, 5 and 6 shorted together.

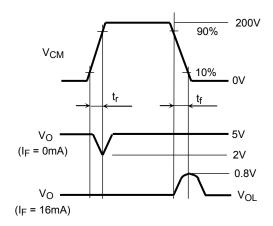
(Note 6) Maximum electrostatic discharge voltage for any pins: 100V(C=200pF, R=0)

Test Circuit 1: Switching Time Test Circuit



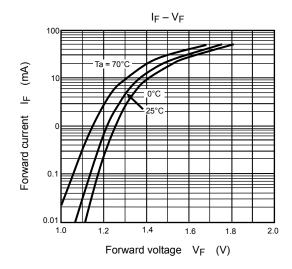
Test Circuit 2: Common Mode Transient Immunity Test Circuit

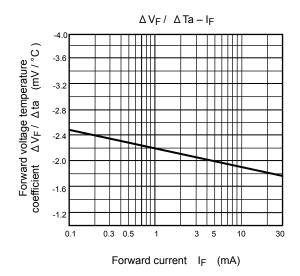


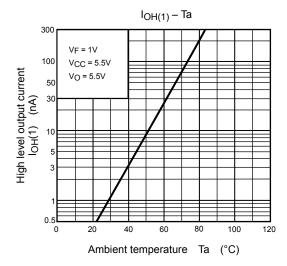


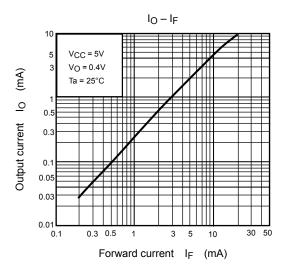
$$CM_{H} = \frac{160(V)}{t_{f}(\mu s)}, CM_{L} = \frac{160(V)}{t_{f}(\mu s)}$$

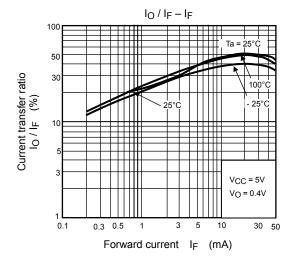
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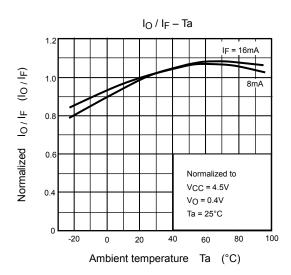




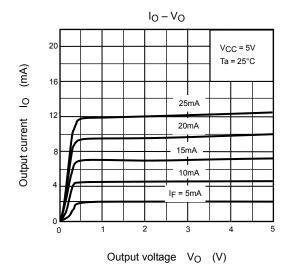


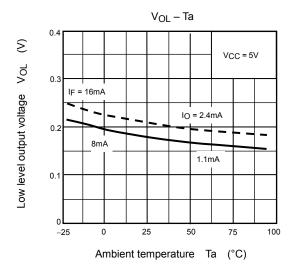


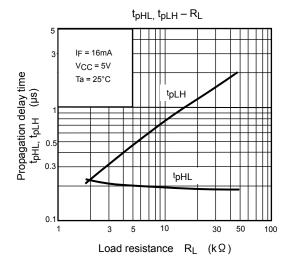


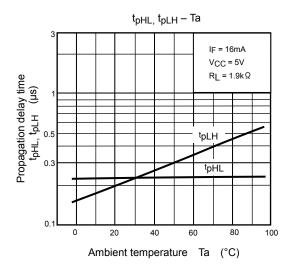


5









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